

60V P-Channel Enhancement Mode MOSFET

Voltage

-60 V

Current

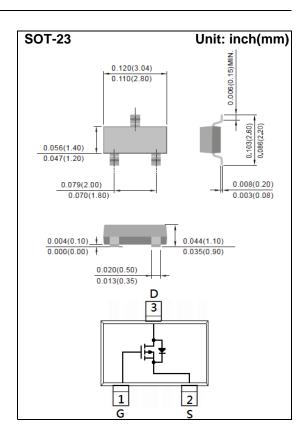
-1.9A

Features

- $R_{DS(ON)}$, $V_{GS}@-10V$, $I_{D}@-1.9A<170m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_{D}@-1.5A<220m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0084 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V _{DS}	-60	- v	
Gate-Source Voltage		V _{GS}	<u>+</u> 20		
Continuous Drain Current (Note 4)	T _A =25°C		-1.9		
	T _A =70°C	I _D	-1.5	Α	
Pulsed Drain Current (Note 1)		I _{DM}	-7.6		
Power Dissipation	T _A =25°C		1.25	W	
	T _A =70°C	P _D	0.8		
Single Pulse Avalanche Energy (Note 6)		Eas	32	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 4,5)		Reja	100	°C/W	



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-60	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.88	-2.5		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-1.9A	-	140	170	mΩ	
		V _{GS} =-4.5V, I _D =-1.5A	-	190	220		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0V	-	-	-1	uA	
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 12V, V _{DS} =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 7)							
Total Gate Charge	\mathbf{Q}_{g}		-	8.3	-	nC	
Gate-Source Charge	Q_gs	V _{DS} =-30V, I _D =-1.9A, V _{GS} =-10V (Note 2,3)	-	1.8	-		
Gate-Drain Charge	Q_gd	VGS=-10V (1000 2,0)	-	1.6	-		
Input Capacitance	Ciss	\/ 00\/ \/ 0\/	-	430	-	pF	
Output Capacitance	Coss	V _{DS} =-30V, V _{GS} =0V, f=1.0MHZ	-	33	-		
Reverse Transfer Capacitance	Crss	I=1.0IVIDZ	-	29	-		
Turn-On Delay Time	td _(on)	\/ 00\/ I 4A	-	5.1	-		
Turn-On Rise Time	tr	V_{DD} =-30V, I_{D} =-1A, V_{GS} =-10V, R_{G} =6 Ω (Note 2,3)	-	20	-	ns	
Turn-Off Delay Time	td _(off)		-	36	-		
Turn-Off Fall Time	tf	RG=012 (Note 2,6)	-	11	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	I.			-	-1.5	Α	
Diode Forward Current (Note 3)	I _S		_				
Diode Forward Voltage	V_{SD}	Is=-1A, V _{GS} =0V	-	-0.78	-1	V	

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited.
- 5. Roja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. The test condition is L=1mH, I_{AS} =-8A, V_{DD} =-25V, V_{GS} =-10V.
- 7. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

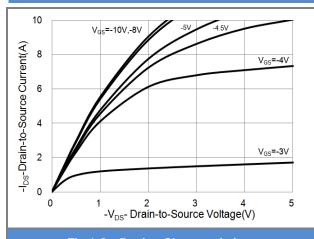


Fig.1 On-Region Characteristics

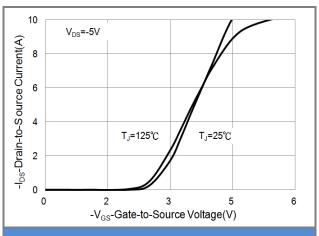


Fig.2 Transfer Characteristics

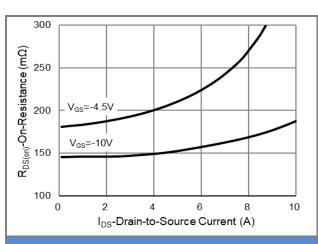


Fig.3 On-Resistance vs. Drain Current

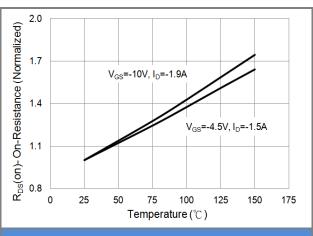
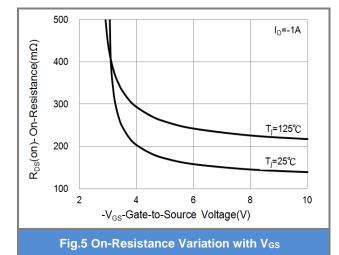
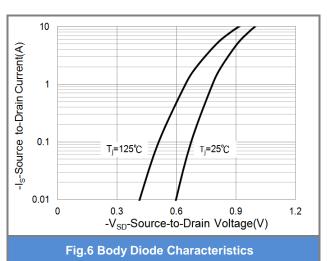


Fig.4 On-Resistance vs. Junction temperature



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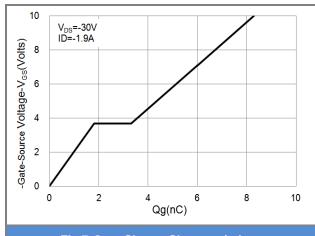


Fig.7 Gate-Charge Characteristics

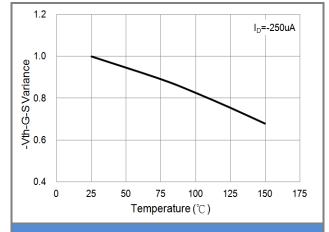


Fig.8 Threshold Voltage Variation with Temperature

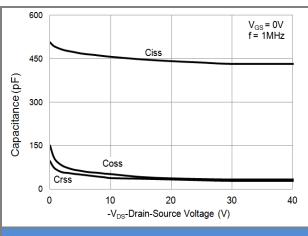


Fig.9 Capacitance vs. Drain-Source Voltage

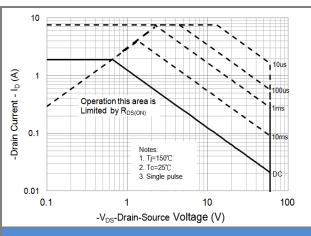


Fig.10 Maximum Safe Operating Area

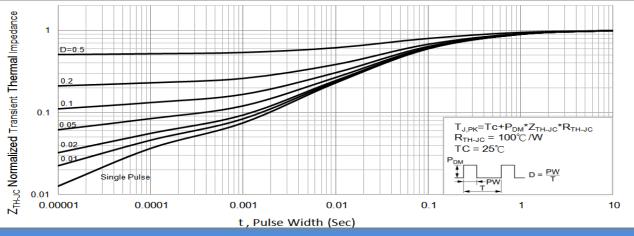


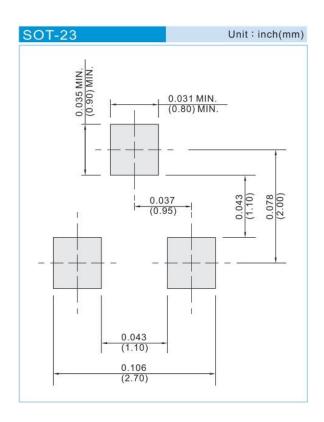
Fig.11 Normalized Transient Thermal Impedance vs. Pulse Width



Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJA3461-AU	SOT-23	3K pcs / 7" reel	A61	

Mounting Pad Layout





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